

**Practitioner's Docket No.:** 811\_107

**PATENT**

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re the Application of: Makoto IWAI, Katsuhiro IMAI and Minoru IMAEDA

Serial No.: 10/594,846

Art Unit: 1792

Dated Filed: November 8, 2006

Examiner: G. Nagesh Rao

Confirmation No.: 3664

For: GALLIUM NITRIDE SINGLE CRYSTAL GROWING METHOD AND  
GALLIUM NITRIDE SINGLE CRYSTAL

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**AMENDMENT AFTER NON-FINAL REJECTION**

Sir:

In response to the Office Action mailed February 25, 2010, please amend the  
above-identified application as follows:

**Amendments to the Claims** are reflected in the listing of claims which begins  
on page 2 of this paper.

**Remarks/Arguments** begin on page 4 of this paper.